Giant nonlinear optical effects induced by nitrogen-vacancy centers in diamond crystals

Mari Motojima, Takara Suzuki, Hidemi Shigekawa, Yuta Kainuma, Toshu An, and Muneaki Hase

1Department of Applied Physics, Faculty of Pure and Applied Sciences, University of Tsukuba, 1-1-1 Tennodai, Tsukuba 305-8573, Japan
2School of Materials Science, Japan Advanced Institute of Science and Technology, Nomi, Ishikawa 923-1292, Japan

We investigate the effect of nitrogen-vacancy (NV) centers in single crystal diamond on nonlinear optical effects using 40 fs femtosecond laser pulses. The near infrared femtosecond pulses allow us to study purely nonlinear optical effects, such as optical Kerr effect (OKE) and two-photon absorption (TPA), relating to unique optical transitions by electronic structures with NV centers. It is found that both the nonlinear optical effects are enhanced by the introduction of NV centers in the N\(^+\) dose levels of 2.0×10\(^{11}\) and 1.0×10\(^{12}\) N\(^+/\)cm\(^2\). In particular, our data demonstrate that the OKE signal is strongly enhanced for the heavily implanted type-IIa diamond. We suggest that the strong enhancement of the OKE is possibly originated from cascading OKE, where the high-density NV centers effectively break the inversion symmetry near the surface region of diamond.

INTRODUCTION

The optical and magnetic properties of the negatively charged nitrogen-vacancy (NV) center in diamond have been extensively investigated because of its potential application to quantum sensing [1], such as magnetic and electric fields [2, 3], local temperature in bio-systems [4], and to quantum information technologies [5]. In most cases, near-infrared luminescence upon the excitation by green laser can be controlled by the irradiation of microwave, which tunes the optical transition paths between the excited and ground states [6]. To extend the optical property of diamond over the current generation of linear optical regime, one requires ultrashort laser pulses, which enables us to induce coherent lattice vibrations [7-10] as well as nonlinear optical effect, such as the nonlinear refraction and nonlinear absorption [11-13]. Almeida et al recently reported on nonlinear optical spectra in high-purity diamond using femtosecond laser pulses with photon energy from 0.83 to 4.77 eV and measured coefficients for the nonlinear refraction and nonlinear absorption [12]. Because of the absence of defect-related bands below the band-gap (E\(_g\) = 5.5 eV), the two nonlinear optical effects were enhanced for the photon energy of h\(\omega\) = E\(_g\)/2. Although there are several investigations on nonlinear optical effects in bulk diamond and nano-diamond [14, 15], the effects of the NV center on the nonlinear optical phenomena have not yet been examined. However, this issue is important to further study new functionality of diamond photonics to advance nonlinear quantum sensing.

Here we explore the NV center induced nonlinear optical effects in pure diamond, specifically optical Kerr effect (OKE) and two-photon absorption (TPA) in transparent region using 800 nm light, at which NV related bands will be sensitive. It is found that both the nonlinear optical effects are enhanced by the introduction of NV centers. Importantly, the signal enhancement is more visible for the time-resolved reflectivity measurement than that in the case of the conventional transmission measurements.

EXPERIMENTAL

We first carried out Z-scan measurement to examine nonlinear optical effects, such as OKE and TPA [16]. The Z-scan measurements were performed using a closed aperture mode, to study the nonlinear refraction and nonlinear absorption, respectively. As shown in Fig. 1(a), the transmittance of a diamond sample through an aperture (a diameter of 0.8 mm) in the far-field was measured as a function of the sample position \(z\) with respect to the focal plane. The light source used was a femtosecond regenerative amplifier system (RegA9040, Coherent), which produces \(\approx 40\) fs pulses at a central wavelength of \(\lambda\approx800\) nm with an average power of \(\approx500\) mW at 100 kHz repetition rate. The output of the amplifier was focused via a focal length \(f = 50\) mm lens into the samples. Z-scan measurement enables us to evaluate the nonlinear optical effects associated with the third-order nonlinear susceptibility \(\chi^{(3)}\) from its transmittance change. The third-order nonlinear susceptibility can be expressed by:

\[
\chi^{(3)} = \chi^{(3)}_{\text{bulk}} + \chi_{NV}^{(3)} + \chi_{NV}^{(2)}\chi_{NV}^{(2)},
\]

where the first term \(\chi^{(3)}_{\text{bulk}}\) describes bulk third-order susceptibility, the second term \(\chi_{NV}^{(3)}\) represents NV-induced third-order susceptibility, and the last term suggests a possible contribution from the cascaded second-order susceptibility \(\chi_{NV}^{(2)}\) [11, 17, 18], which may be detected by
surface sensitive optical methods, such as optical reflectivity. Note that the second-order susceptibility $\chi^{(2)}$ is generally zero whenever the material has inversion symmetry, i.e., in the case for high purity diamond. The inversion symmetry can be, however, broken when NV centers are introduced, since the N atom and its adjacent vacancy break the inversion symmetry of the diamond crystal [19]. Eq. (1) is expected to be affected by both the OKE and TPA via $\Re \chi^{(3)} = 2n_2^2 c n_0$ and $\Im \chi^{(3)} = n_2^2 c / k$, respectively, where $n_2$ is the non-linear refraction, $n_0$ is the linear refraction coefficient, $\epsilon_0$ is the vacuum permittivity, $c$ is the speed of light in vacuum, $\beta$ represents nonlinear absorption (TPA) coefficient, and $k$ denotes the wave vector [11, 16].

To investigate the time-domain response from the OKE and TPA due to the NV centers near the sample surface, reflection-type pump-probe measurements for the diamond samples were also carried out using the same femtosecond regenerative amplifier system at room temperature by employing the fast scanning time-delay method [Fig. 1(b)] [20]. The pump and probe beams were focused via the focal length $f = 100$ mm lens onto the sample surface with a mutual angle of $\leq 5^\circ$. The pump power was varied from 20 to 80 mW, while the probe power was kept at $\leq 2$ mW. Polarization of the two beams was linear with orthogonal each other.

The samples used were Element Six [100] type-IIa diamond crystal fabricated by CVD method, whose impurity (nitrogen: [N] and boron: [B]) levels were [N] $< 1$ ppm and [B] $< 0.05$ ppm, respectively. The sample size was 3.0 mm$\times$3.0 mm$\times$0.3 mm (thickness). To introduce NV centers 30 keV nitrogen ions ($N^+$) were implanted into the diamond samples at the $N^+$ dose levels of $2.0 \times 10^{11}$ and $1.0 \times 10^{12}$ ions/cm$^2$. The implanted depth deduced from the Monte Carlo calculation (TRIM) was about 30–40 nm [21, 22] and the profile was close to a Gaussian function with FWHM of $\sim 50$ nm. After that, the samples were annealed at 900–1000 °C in an argon atmosphere for 1 hour to produce NV centers with a production efficiency of $\approx 1\%$ (see Fig. 2) [23]. The production of NV centers was confirmed by optically-detected magnetic resonance (ODMR) technique using a 532 nm laser at $\approx 1$ mW [22].

RESULTS AND DISCUSSION

Figure 3 shows the results of the closed-aperture Z-scan measurements obtained for different $N^+$ dose levels observed at the laser fluence of $I_0 \approx 20$ mJ/cm$^2$. Anti-symmetric line shape, whose peak and valley have not the same amplitude, was observed for all the samples. The anti-symmetric lineshape, with a valley greater than the peak, indicates an existence of two-photon absorption [13]. The intensity of the transmittance change becomes larger when the NV centers were introduced at $2.0 \times 10^{11}$ and $1.0 \times 10^{12}$ $N^+$/cm$^2$. In particular, the valley at $z = -0.2$ mm exhibits $\approx 1.3$ times larger transmission change.
compared to the pure diamond (non-implanted), indicating that absorption by NV centers plays a central role in the enhancement of the signals in Figs. 3(b) and 3(c).

FIG. 3. Closed-aperture Z-scan results at $I_0=20\,\text{mJ/cm}^2$ obtained for the pure diamond crystal and NV center introduced diamond at different dose levels, (a) non-implanted, (b) $2\times10^{13}\text{N}^+/\text{cm}^2$, and (c) $1\times10^{12}\text{N}^+/\text{cm}^2$. The black solid lines represent the fit to the data using Eq. (2).

We applied the general model of the Z-scan technique for the transmittance change [16, 24].

$$T(x) = 1 + \frac{4x}{(x^2 + 9)(x^2 + 1)} \Delta \phi_0 - \frac{2(x^2 + 3)}{(x^2 + 9)(x^2 + 1)} \Delta \psi_0,$$  

(2)

where $x = \frac{z}{z_0}$, $z$ is the position, $z_0 = \frac{\pi w_0^2}{\lambda}$ is the Rayleigh length with $w_0$ being the beam waist, $\Delta \phi_0$ is induced phase shift and $\Delta \psi_0$ is a loss parameter. The parameters obtained by the fitting are listed in Table 1. The fitting parameter of $z_0 \sim 0.2\,\text{mm}$ corresponds to $w_0 \sim 7\,\mu\text{m}$, a value being well consistent with that calculated ($\sim 8\,\mu\text{m}$) using $w_0 = 0.61\lambda/NA$, where $NA = 0.06$ is the numerical aperture of the lens used. As seen in Table 1, the phase shift $\Delta \phi_0$ associated with nonlinear refraction $n_2$ becomes larger by a factor of $\approx 1.3$ when the NV centers were introduced, while $\Delta \psi_0$ associated with nonlinear absorption $\beta$ (e.g., two-photon absorption) is enhanced by a factor of $\approx 1.6$. Thus, we can see the small but significant increases in the nonlinear optical effects associated with the NV center on the Z-scan data, which corresponding to $\chi^{(3)}_{NV}$ in Eq. (1). To study further details, we used the relationships between the fitting parameters, $\Delta \phi_0$ and $\Delta \psi_0$, and nonlinear optical effects, which are $\Delta \phi_0 = k n_2 I_0 L_{\text{eff}}$ and $\Delta \psi_0 = \beta I_0 L_{\text{eff}}/2$ [16], where $L_{\text{eff}}$ is the effective length of the sample defined by $(1-e^{-\alpha L})/\alpha$ with $\alpha (\approx 0.1\,\text{cm}^{-1})$ [25], the linear absorption coefficient and $L$ (0.3 mm) the sample length. Using these relations, we obtain $n_2 = 4.16 \times 10^{-20}\text{m}^2/\text{W}$ for the non-implanted diamond and $n_2 = 5.50 \times 10^{-20}\text{m}^2/\text{W}$ for the NV center introduced diamond at $1.0 \times 10^{12}\text{N}^+/\text{cm}^2$. In the same way, we obtain $\beta = 0.993 \times 10^{-2}\text{cm/GW}$ for the non-implanted diamond and $\beta = 1.61 \times 10^{-2}\text{cm/GW}$ for the NV center introduced diamond at $1.0 \times 10^{12}\text{N}^+/\text{cm}^2$. These values are the same order of those obtained for high purity diamond [13]. Although the NV introduced samples exhibit the small enhancement of the nonlinear optical effects, the transmission mode might dominantly detect the bulk contribution $\chi^{(3)}_{\text{bulk}}$, and masked the precise signal from NV centers, $\chi^{(3)}_{NV}$ and $\chi^{(2)}_{NV}$, which are buried in the sample surface. To examine the precise effect of $\chi^{(3)}_{NV}$ and $\chi^{(2)}_{NV}$, we show the results on the transient reflectivity measurements below.

Figure 4 shows the results of the time-resolved transient reflectivity ($\Delta R/R$) obtained by the pump-probe technique. The $\Delta R/R$ signal consists of an instantaneous drop, where the width of the negative peak (FWHM of $\approx 50\,\text{fs}$) obtained by a Gaussian fit and deconvolution nearly corresponds to the pulse duration of the laser used. The effectively smaller FWHM of the $\Delta R/R$ signal than that observed in a highly pure diamond [13] and that of the transient transmission ($\Delta T/T$) using UV excitation [24] suggests the fact that the pulse duration in the present study is shorter than those in the literatures and the origin of the signal is due to nonlinear optical effects, such as OKE and TPA, which are governed by non-resonant intermediate states [11].

![FIG. 4. Pump-probe reflectivity results obtained for the different dose levels of CVD diamond crystals at $I_0=30\,\text{mJ/cm}^2$.](image)

The standard deviation of coefficients were obtained during the fitting procedure with Igor Pro.

<table>
<thead>
<tr>
<th>Sample</th>
<th>$\Delta \phi_0$ (m rad)</th>
<th>$\Delta \psi_0$ (m rad)</th>
<th>$z_0$ (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Diamond (non-implanted)</td>
<td>0.39±0.01</td>
<td>0.06±0.01</td>
<td>0.22±0.01</td>
</tr>
<tr>
<td>Diamond $(2.0 \times 10^{13}\text{N}^+/\text{cm}^2)$</td>
<td>0.53±0.02</td>
<td>0.08±0.01</td>
<td>0.22±0.01</td>
</tr>
<tr>
<td>Diamond $(1.0 \times 10^{12}\text{N}^+/\text{cm}^2)$</td>
<td>0.52±0.01</td>
<td>0.10±0.01</td>
<td>0.20±0.01</td>
</tr>
</tbody>
</table>

TABLE I. The fitting parameters obtained using Eq. (2).
oscillations due to the generation of coherent optical phonons were not observed because of longer pulse width (≈ 40 fs) than that (≈ 10 fs) needed for the observation of the 40 THz coherent optical phonon \( R \). Now the several times larger \( \Delta R/R \) signal observed in the NV center introduced diamond indicates that the origin of the signal increase comes from the surface region rather than the bulk, since the signal enhancement was much smaller when we observed the transmittance by the Z-scan technique, in which we observe the nonlinear optical effects dominated by the native [N] and [B] defects in the bulk region. Note that we have also observed the \( \Delta T/T \) signal using the pump-probe technique (data not shown). In this case, however, the factor of the signal enhancement was only less than several tens percent as in the case of the Z-scan measurements. Thus, the largest signal enhancement was observed only for the transient reflectivity signal, indicating that the signal enhancement is due to NV centers localized in the surface region.

Under the assumption that the linear absorption (one-photon) for the near infrared light (\( \lambda \approx 800 \text{ nm} \)) can be neglected and the incident angle of the probe beam is the sample normal, the transient reflectivity change induced by the nonlinear optical effects can be expressed by the change in the real part of the refractive index \( \Delta n \) \[27]\:

\[
\frac{\Delta R}{R} = \frac{4}{n_0^2 - 1} \Delta n \approx 0.84 (\Delta n_{\text{OKE}} + \Delta n_{\text{TPA}}),
\]

where \( n_0 = 2.4 \) for diamond at \( \lambda \approx 800 \text{ nm} \) was taken \[28\]. Here, \( \Delta n \) is modulated by OKE, \( \Delta n_{\text{OKE}} = n_2 I_0 \) \[11\], and free carrier contribution via TPA, \( \Delta n_{\text{TPA}} \), whose intensity dependence can be expressed as below based on the Drude model \[27]\:

\[
\Delta n_{\text{TPA}} = -\frac{2\pi e^2 N}{n_0 m^* \omega^2} \frac{\beta I_0^2}{2 \hbar \omega \tau_p} = \kappa \beta I_0^2.
\]

where \( e \) is the electron charge, \( N \) is the free carrier density, \( m^* \) is the electron effective mass, \( \omega \) is the angular frequency of the laser used, \( \tau_p \) is the pulse length, and \( \kappa = -2\pi e^2/(n_0 m^* \omega^2 \cdot 2 \hbar \omega \tau_p) \). As the pump fluence increases, nonlinear increase in the \(|\Delta R/R|\) signal was observed for all the diamond samples, as shown in Fig. 5. By fitting the \(|\Delta R/R|\) signals using a function of \( a I_0 + b I_0^2 \), we obtained the fitting parameters \( a \) and \( b \) for different NV densities. Then, using the relationships from Eqs. (3) and (4), i.e. \( a = 0.84 n_2 \) and \( b = 0.84 |\beta| \), the values of \( n_2 \) and \( \beta \) are obtained as listed in Table 2. Although the value of \( \beta \) shows small increase as the \( N^+ \) dose is increased, the value of \( n_2 \) associated with OKE increases more than an order of magnitude for the case of the heavily implanted diamond, \( 1.0 \times 10^{12} \text{ N}^+/\text{cm}^2 \). Note that the observed \( n_2 \) was negative in our study, which would be due to the contribution from cascading OKE as discussed in more details in the latter sections. Hereafter, we will discuss the value of \( |n_2| \) to examine the effect of the NV center in diamond. The \( |n_2| \) in Table 2 obtained for the non-implanted and the lightly implanted diamond (\( 2.0 \times 10^{11} \text{ N}^+/\text{cm}^2 \)) are very small if we consider the standard deviations, but are in good agreement with those obtained by Z-scan measurements by other groups \[13, 29\].

On the other hand, the quadratic dependence of the \(|\Delta R/R|\) signal observed in the present study is surprisingly coincide with the signal from photo-carriers generated upon green laser (532 nm) illumination as the function of the green laser power \[30\]. Bourgeois et al. have detected two-photon excited free electrons in the conduction band (CB) as the photocurrent (photo-carriers) both in type-Ib and -IIa CVD diamonds \[30\]. Since the quadratic dependence was enhanced for the pure type-IIa diamond, they concluded that the linear dependence dominated for the type-Ib diamond came from one-photon absorption via \( N_0^S \) defect state \[31\]. In our case, i.e., type-IIa diamond, however, the \( N_0^S \) de-

| Non-implanted | \( 0.73 \pm 0.63 \) | \( 0.90 \pm 0.06 \) |
| 2.0 \times 10^{11} \text{ N}^+/\text{cm}^2 | \( 1.20 \pm 0.90 \) | \( 1.75 \pm 0.09 \) |
| 1.0 \times 10^{12} \text{ N}^+/\text{cm}^2 | \( 24.2 \pm 0.50 \) | \( 1.01 \pm 0.05 \) |

FIG. 5. Pump fluence dependence of the \(|\Delta R/R|\) signal observed in diamond samples. The solid curves are the fit using a function of \( a I_0 + b I_0^2 \).
fects rarely exist and therefore the effect of \( N_0 \) defect states is negligible. Thus, the linear dependence on the \( | \Delta R / R | \) signal should be dominated by the OKE. Thus, our data demonstrate that the OKE signal is enhanced much in the case of heavily implanted type-IIa diamond (1.0 \times 10^{12} \text{N}^+/\text{cm}^2). A possible reason for the giant enhancement of the OKE is the contribution from the cascading OKE 11, 17, 18, whose nonlinear susceptibility is expressed by \( \chi^{(2)}_{NV} \chi_{XY} \) as in Eq. (1); the high density NV centers can effectively break the inversion symmetry near the sample surface region. Note that non-zero \( \chi^{(2)} \) would generate second-harmonic generation (SHG) and therefore the incident pump photon energy cannot fully be supplied for the competing TPA 32. In the case of the nonlinear refraction (e.g., cascading OKE), the coherence length \( L_{coh} \) might be important, which is \( \sim 16 \mu\text{m} \), obtained using \( L_{coh} = \pi / \Delta k \), where \( \Delta k = k_2 - k_\omega \) is the wave vector mismatch during SHG 32. In the case of the nonlinear absorption (e.g., TPA) via Im\( \chi^{(3)} \), the Rayleigh length (\( z_0 \approx 200 \mu\text{m} \) in the present study) would play a major role. However, considering the signal enhancement occurred in the region where NV centers exist and inversion symmetry was broken (\( \chi^{(2)} \neq 0 \)), our data indicate that the NV center introduced surface region with \( L_{NV} \sim 60-70 \text{nm} \) thick in maximum play a dominant role.

By contrast, the nonlinear absorption, \( \beta \), shows a largest value for the lightly implanted diamond (2.0 \times 10^{11} \text{N}^+/\text{cm}^2), indicating the stronger absorption of the probe light upon the photoexcitation, which can be discussed based on the band model of NV centers 32, 33. Since the band-gap energy (\( E_g = 5.5 \text{ eV} \)) of diamond is much larger than the photon energy used (1.55 eV), and for high-purity diamond the two-photon absorption starts from \( \approx E_g / 2 \) 13, it is required to consider the mid-gap states associated with the NV centers, which locates in between the band-gap, as illustrated in Fig. 6 33. For the negatively charged NV\(^-\) state, the two-photon absorption (1.55 + 1.55 eV) would promote an electron from the \( ^3\text{A}_2 \) ground state into the CB 30. In this case, the two-photon absorption induces free carrier generation in the CB, and then immediately transfers the NV\(^-\) to NV\(^0\) states, i.e., the ionization 37 (see Fig. 6). Therefore, the existence of the NV centers will promote strong two-photon absorption as the pump action in the initial NV\(^-\) state and subsequent transient one-photon absorption of a 1.55 eV probe photon by free carriers, which would induce a few times larger \( \Delta R / R \) signal observed in NV center introduced diamond at 2.0 \times 10^{11} \text{N}^+/\text{cm}^2 (Fig. 4). Note that the ionization and/or recombination from the NV\(^-\) to NV\(^0\) states or vise versa have been discussed under the green laser (532 nm) irradiation 37, 38. There, both the ionization (NV\(^-\) \rightarrow NV\(^0\)) and recombination (NV\(^0\) \rightarrow NV\(^-\)) rates exhibited quadratic dependence on the green laser power for relatively low densities of NV centers (type-IIa, [N] < 1 ppm) 38. The laser wavelength used in the present study is, however, near infrared (800 nm), and it is not possible to induce the recombination with such a low photon energy (see Fig. 6, right panel). It is to be also noted that the transient \( \Delta R / R \) signal observed in the present study is dynamical phenomenon, originating dominantly from the initial NV\(^-\) state, and contribution from the NV\(^0\) state to the \( \Delta R / R \) signal will be negligibly small, although further experiments using different photon energies and theoretical analysis are required to fully understand the ultrafast nonlinear dynamics in diamond. In addition, for the heavily implanted diamond, the energy loss due to the SHG will be largest for the highest dose of 1.0 \times 10^{12} \text{N}^+/\text{cm}^2, and thereby the
probability of TPA would be decreased. This would explain why the $\beta$ value associated with the TPA decreases at $1.0 \times 10^{12}$ N$^+$/cm$^2$ in Table 2.

**CONCLUSION**

We investigate the effect of nitrogen-vacancy (NV) centers in diamond on nonlinear optical effects using 40 fs femtosecond laser pulses. The near infrared femtosecond pulses allow us to study purely nonlinear optical absorption, relating to unique optical transitions by electronic structures involved with NV centers. It is found that both the nonlinear optical effects are enhanced by the introduction of NV centers in the N$^+$ dose levels of $2.0 \times 10^{12}$ and $1.0 \times 10^{12}$ N$^+$/cm$^2$. The signal enhancement was more visible for the time-resolved reflectivity measurements ($\Delta R/R$) than that in the case of the conventional transmission ($T$) measurements by the Z-scan technique. We attribute the several times larger signal enhancement in the $\Delta R/R$ mode observed at N$^+$ dose levels of $1.0 \times 10^{12}$ N$^+$/cm$^2$ to dominant contribution from the cascading OKE originating from breaking the inversion symmetry near the surface region, and minor one from TPA due to the NV$^-$ bands in diamond. Our results will open the new window to develop all optical quantum technologies in a wide range of spatial and frequency resolutions.

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* mhase@bk.tsukuba.ac.jp